



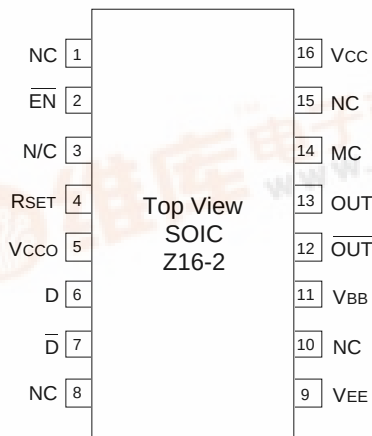
LASER DIODE DRIVER WITH OUTPUT ENABLE

PRELIMINARY
SY100EL1003

FEATURES

- Up to 1.25Gbps operation
- 75mA peak drive current
- Separate modulation control
- Separate output enable for laser safety
- Differential inputs for data
- 75K Ω input pulldown resistor
- Single power supply
- Available in 16-pin SOIC package

PIN CONFIGURATION



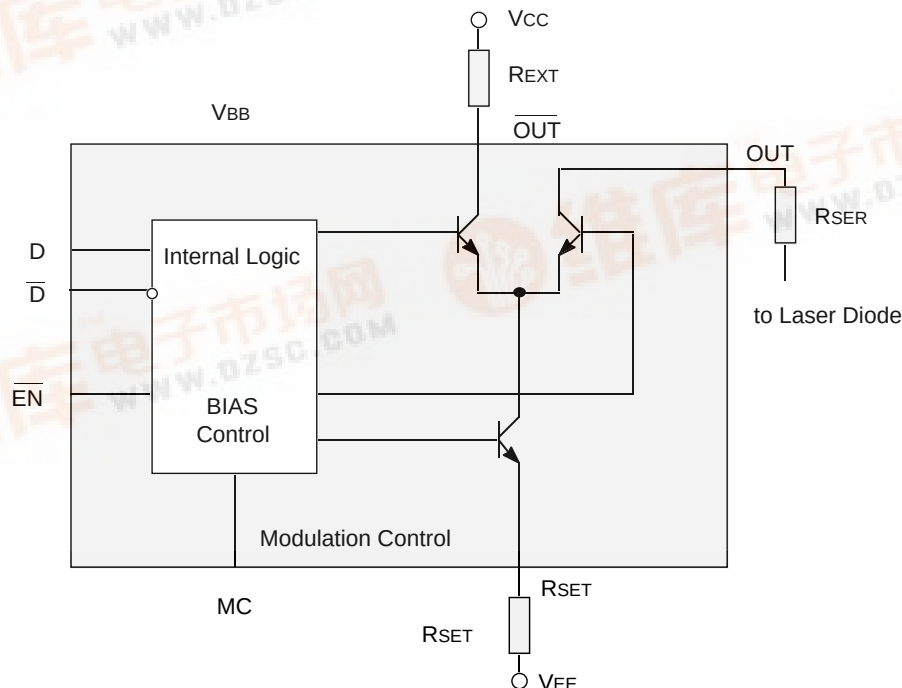
DESCRIPTION

The SY100EL1003 is a high speed current source for driving a semiconductor laser diode in optical transmission applications. The output current modulation is DC – voltage controlled. The modulation current is disabled when output enable is HIGH.

The device incorporates complementary open collector outputs with a capability of driving peak current of 75mA. The laser driver current is adjustable by selection of RSET. The resistor REXT must be placed between OUT and VCC to dissipate the worst case power. RSER is recommended to fix laser diode matching issues.

The SY100EL1003 utilizes the high performance bipolar ASSET technology.

BLOCK DIAGRAM



PIN NAMES

Pin	Function
V _{CC} , V _{CCO}	Separate positive power supply pins help to isolate sensitive circuitry from noise generating function. +5V for PECL operation or ground for ECL operation.
V _{EE}	Most negative power supply input. Ground for PECL operation or -5V for ECL operation.
V _{BB}	This pin provides a reference voltage for use in single ended applications or when the input signal is AC coupled into the device.
D, $\overline{D}$	These differential ECL/PECL 100K compatible inputs receive NRZ data.
$\overline{EN}$	This ECL/PECL 100K compatible input enables Laser Driver - modulation current transitions to zero when asserted HIGH.
OUT, $\overline{OUT}$	Open collector outputs from the modulation buffer drive these differential current outputs.
MC	An external voltage sets the main value of modulation current I _o .
RSET	An external resistor sets the source current for modulation I _{mod} .
NC	These pins are not connected.

TRUTH TABLE⁽¹⁾

D	$\overline{D}$	$\overline{EN}$	OUT	$\overline{OUT}$
L	H	L	H	L
H	L	L	L	H
X	X	H	H	L

NOTE:

1. L = LOW, H = HIGH, X = don't care

ABSOLUTE MAXIMUM RATINGS⁽¹⁾

Symbol	Rating	Value	Unit
V _{EE}	Power Supply Voltage (V _{CC} = 0V)	0 to -7.0	V
V _I	Input Voltage (V _{CC} = 0V)	0 to -6.0	V
I _O	Output Current	75	mA
T _A	Operating Temperature Range	-40 to +85°	°C
P _{tot}	Power Dissipation	500	mW

NOTE:

1. Permanent device damage may occur if ABSOLUTE MAXIMUM RATINGS are exceeded. This is a stress rating only and functional operation is not implied at conditions other than those detailed in the operational sections of this data sheet. Exposure to ABSOLUTE MAXIMUM RATING conditions for extended periods may affect device reliability.

OPERATIONING CONDITIONS⁽¹⁾

Symbol	Rating	Value	Unit
V _{EE}	Power Supply Voltage	-4.75 to -5.25	V
RSET	Resistor to Adjust Current	10 to 100	Ω
REXT	Resistor to Dissipate Power	10 to 50	Ω
RSER	Laser Diode Serial Resistor	0 to 50	Ω

NOTE:

1. The voltage drop across REXT and RSER should not be greater than 2V.

DC ELECTRICAL CHARACTERISTICS⁽¹⁾V_{CC} = V_{CCO} = 0V; V_{EE} = -5.0V ± 5%

Symbol	Parameter	T _A = -40°C			T _A = 0°C			T _A = +25°C			T _A = +85°C			Unit
		Min.	Typ.	Max.	Min.	Typ.	Max.	Min.	Typ.	Max.	Min.	Typ.	Max.	
V _{IH}	Input HIGH Voltage (D, $\overline{\text{EN}}$)	-1165	—	-880	-1165	—	-880	-1165	—	-880	-1165	—	-880	mV
V _{IL}	Input LOW Voltage (D, $\overline{\text{EN}}$)	-1810	—	-1475	-1810	—	-1475	-1810	—	-1475	-1810	—	-1475	mV
V _{Imod}	Input Voltage (Modulation Control)	V _{EE}	—	V _{CC}	V _{EE}	—	V _{CC}	V _{EE}	—	V _{CC}	V _{EE}	—	V _{CC}	V
V _{BB}	Output Reference Voltage	-1380	—	-1260	-1380	—	-1260	-1380	—	-1260	-1380	—	-1260	mV
I _{IH}	Input HIGH Current (D, $\overline{\text{EN}}$)	—	—	150	—	—	150	—	—	150	—	—	150	μA
I _{Imod}	Input Current (Modulation Control)	—	—	150	—	—	150	—	—	150	—	—	150	μA
I _{IL}	Input LOW Current ⁽²⁾ (D, $\overline{\text{EN}}$)	0.5	—	—	0.5	—	—	0.5	—	—	0.5	—	—	μA
I _{CC}	Supply Current ⁽³⁾	8	14	25	8	14	25	8	14	25	8	14	25	mA
I _{OH}	Output HIGH Current ⁽⁴⁾ ($\overline{\text{EN}}$ LOW) ⁽⁵⁾	60	64	68	60	64	68	60	64	68	60	64	68	mA 5
I _{OL}	Output LOW Current ($\overline{\text{EN}}$ HIGH)	—	—	500	—	—	500	—	—	500	—	—	500	μA
I _{OR}	Output Current Ringing ⁽⁶⁾	—	—	10	—	—	10	—	—	10	—	—	10	%
I _{Omod}	Laser Diode Modulation Current Range	5	—	60	5	—	60	5	—	60	5	—	60	mA

NOTES:

1. R_{SET} = 10Ω ± 1%
2. V_I = V_{IL}(Min.)
3. V_{Imod} = V_{CC}
4. V_{Imod} = -3.5V
5. V_{Lmod} = -0.8V
6. I_{OH} = 5 to 60mA

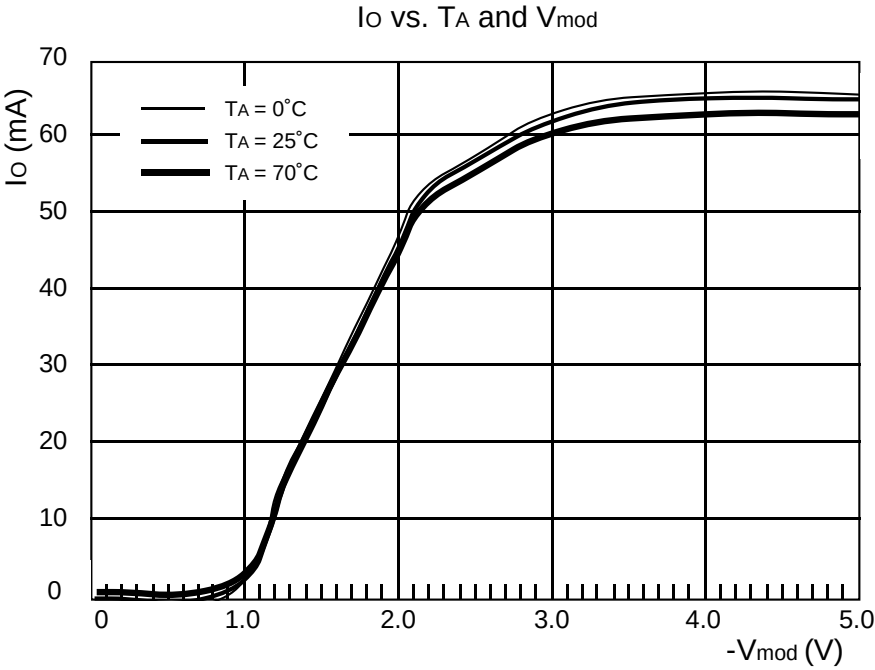
AC ELECTRICAL CHARACTERISTICS⁽¹⁾V_{Imod} = -1.5V; V_{CC} = V_{CCO} = 0V; V_{EE} = -5V ± 5%

Symbol	Parameter	T _A = -40°C			T _A = 0°C			T _A = +25°C			T _A = +85°C			Unit
		Min.	Typ.	Max.	Min.	Typ.	Max.	Min.	Typ.	Max.	Min.	Typ.	Max.	
t _{pd} D	Propagation Delay D - OUT	—	—	1000	—	—	1000	—	—	1000	—	—	1000	ps
t _{pd} $\overline{\text{EN}}$	Propagation Delay $\overline{\text{EN}}$ - OUT	—	—	1000	—	—	1000	—	—	1000	—	—	1000	ps
t _r t _f	Rise/Fall Time (20% to 80%)	—	—	400	—	—	400	—	—	400	—	—	400	ps

NOTE:

1. R_{SET} = 10Ω ± 1%, R_{EXT} = R_{SER} = 50Ω ± 1%

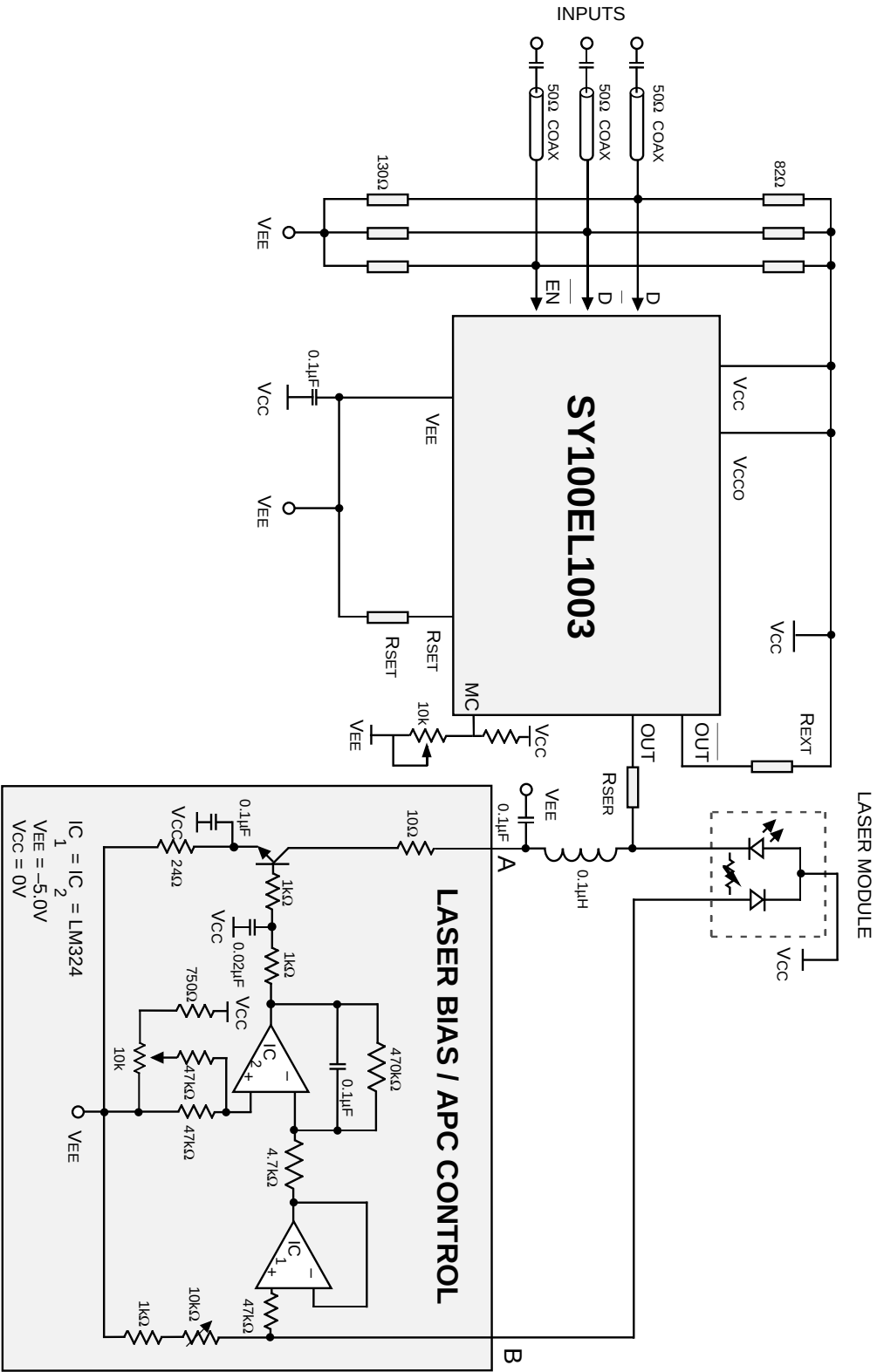
PERFORMANCE CURVES



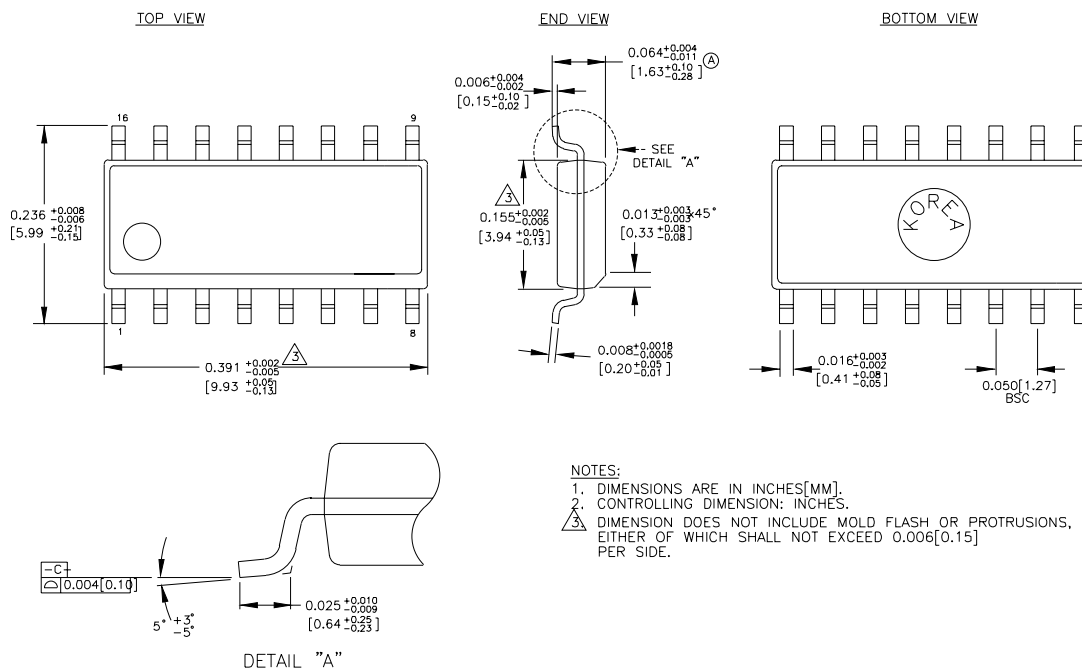
PRODUCT ORDERING CODE

Ordering Code	Package Type	Operating Range
SY100EL1003ZC	Z16-2	Commercial
SY100EL1003ZCTR	Z16-2	Commercial

APPLICATION EXAMPLE



16 LEAD SOIC .150" WIDE (Z16-2)



Rev. 02